Soft Recovery Diode Types M0759Y#040 to M0759Y#160

The data sheet on the subsequent pages of this document is a scanned copy of existing data for this product. (Rating Report 83NR8 Issue 2)

This data reflects the old part number for this product which is: SM02-16CXC190. This part number must **NOT** be used for ordering purposes – please use the ordering particulars detailed below.

> The limitations of this data are as follows: Device no longer available for grade 02 (200V V_{RRM}) Only 'C' outline drawing (W2) in datasheet

The following links will direct you to the appropriate outline drawings Outline W2 – Standard 14.5mm clamp height capsule Outline W3 – 26mm clamp height capsule

Where any information on the product matrix page differs from that in the following data, the product matrix must be considered correct

An electronic data sheet for this product is presently in preparation.

For further information on this product, please contact your local ASM or distributor.

Alternatively, please contact Westcode as detailed below.

Ordering Particulars						
M0759	Y#	**	0			
Fixed Type Code	YC – 14.5mm clamp height YH – 26mm clamp height	Voltage code V _{RRM} /100 04-16	Fixed Code			
Typical Order Code: M0759YC120, 14.5mm clamp height, 1200V V _{RRM}						

IXYS Semiconductor GmbH

Edisonstraße 15 D-68623 Lampertheim Tel: +49 6206 503-0 Fax: +49 6206 503-627 E-mail: marcom@ixys.de

FSTCODE An IXYS Company

IXYS Corporation

3540 Bassett Street Santa Clara CA 95054 USA Tel: +1 (408) 982 0700 Fax: +1 (408) 496 0670 E-mail: sales@ixys.net

www.westcode.com

www.ixys.com

Westcode Semiconductors Ltd

Langley Park Way, Langley Park, Chippenham, Wiltshire, SN15 1GE. Tel: +44 (0)1249 444524 Fax: +44 (0)1249 659448 E-mail: WSL.sales@westcode.com

Westcode Semiconductors Inc

3270 Cherry Avenue Long Beach CA 90807 USA Tel: +1 (562) 595 6971 Fax: +1 (562) 595 8182 E-mail: WSI.sales@westcode.com

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In the interest of product improvement, Westcode reserves the right to change specifications at any time without prior notice

Devices with a suffix code (2-letter, 3-letter or letter/digit/letter combination) added to their generic code are not necessarily subject to the conditions

and limits contained in this report.

QUALITY EVALUATION LABORATORY

Rating Report:

83NR8

(Issue 2)

Date: 1st July, 1986

Origin:

Pages: 22

Diode Type SMO2-16CXC190

Written by:

Checked:

MW) App

Approved:

BLOA.

The CXC190 series of diffused fast recovery diodes is based on a 30 mm diameter slice housed in a cold weld capsule. Alternative ratings are included in this Report for use with either the single or double side cooling beam clamp (400Kg.f), or the single side cooling box clamp assembly (365Kg.f) in addition to the full pressure ratings up to 1000Kg.f. This Report supersedes Rating Report 83NR8 Issue 1.

Ratings

Voltage Grades	: 2-16
V _{RSM}	: 300_1700V
V RRM	
$I_{F(AV)}$: Single phase, 50 Hz, 180° Sinewave	: 200 - 1600V
Double side cooled, $T_{HS} = 55^{\circ}C$; $100^{\circ}C$) Minimum	
, and the second of the second	: 760A, 345A
Single side cooled, $T_{HS} = 100^{\circ}C$) force = 1 Double side cooled) 530Kg.f	: 190A
-F(rmc) boubte Stat Courted /	: 1,540A
$I_{F(d.c)}$ Double side cooled) $I_{HS} = 25^{\circ}C$: 1,245A
I _{F(AV);} Single phase, 50 Hz, 180°C Sinewave)	ė v
Double side cooled, $T_{HS} = 55^{\circ}C$, $100^{\circ}C$) mounting	: 645A , 286A
Single side cooled, $T_{HS} = 100^{\circ}C$) force =	: 165A
$I_{\text{F(rms)}}$ Double side cooled, $I_{\text{HS}} = 25^{\circ}\text{C}$) 365Kg.f	: 1,31OA
$I_{F(d.c)}$ Double side cooled, $I_{HS} = .25^{\circ}C$: 1, 050A
$I_{FSM}: t = 10 ms \; half \; sinewave; \; T_J \; (initial) = 125 C;$	
$V_{RM} = 0.6V_{RRM(MAX)}$: 9,500A
I_{FSM} : t = 10ms half sinewave; I_{J} (initial) = 125°C;	
V _{RM} <10V	: 10,450A
1^{2} t : t = 10ms; T _J (initial) = 125°C; V _{RM} = 0.6V _{RRM(MAX)}	: 0.45 x 10 ⁶ A ² SECS
I^2 t : t = 10ms; I_J (initial) = 125°C; $V_{RM} < 10V$: 0.546 x 10 ⁶ A ² SECS
$I^{2}t : t = 3ms; T_{J} (initial) = 125^{\circ}C; V_{RMi} < 10V$	$0.404 \times 10^6 \text{A}^2 \text{SECS}$
T _{HS} Operating range	: -40 to +125°C
T _{stq} : Non-operating	: -40 to +150°C
	40 to 4130 t

Characteristics

(Maximum values unless stated otherwise)

V _D : T _J = 125 ^o C	:	1.13V
$r_s : T_J = 125^{\circ}C$:	0.38mohms
$V_{\text{FM}} : I_{\text{FM}} = 1500A ^{\text{T}} \text{VJ} = 125^{\circ} \text{C}$:	1.7V
R _{th} (J-HS) Double side cooled, mounting force (365-530Kg.f)	:	0.0625 ⁰ C/W
(530 ~ 1000Kg.f)	:	0.05°C/W
Single side cooled, mounting force (365-530Kg.f)	:	0.125°C/W
(530 - 1000Kg.f)	:	0.1 ⁰ C/W
I_{RRM} : $T_J = 125^{\circ}C$ $V_{RM} = V_{RRM(MAX)}$:	50mA
$Q_{rr}: I_{FM} = 550A; dI/dt = 40A/uS$:	55uC
$V_{RM} = 50V T_{VJ} = 125^{\circ}C$:	
${ m t}_{ m rr}$ (conditions as above)	:	2uS
Mounting force	:	365-1000Kg.f
Outline Drawing	: 1	OOA291
JEDEC No.		0200AA

CONTENTS

	<u>Page</u>
Ratings and Characteristics	1, 2
Voltage Grade Table	4
(2) <u>Introduction</u>	5
(3) <u>Notes on the Ratings</u>	
(a) Square-wave ratings	5
(b) Energy per pulse characteristics	5
(4) Reverse Recovery Loss	
(a) Determination by Measurement	5
(b) Design Method	6
Limit Forward Characteristic	7
Transient Thermal Impedance	8
Surge Rating	9
Recovered Charge	10
5. Factor	11
Reverse recovery energy per pulse	12
Square wave frequency rating 85°C Sin k 200A/uS	13
Square wave frequency rating 55°C Sink 200A/uS	14
Square wave frequency rating 85°C Sink 100A/uS	15
Square wave frequency rating 55°C Sin k 100A/uS	16
Energy per pulse 200A/uS	17
nergy per pulse 100A/uS	18
Sine wave frequency rating 85°C Sink	19
Sine wave frequency rating 55°C Sink	20
ine wave energy per pulse	21
utline drawing	
•	22

CHANGES TO RATING REPORT 83NR8

Page 12 E_{r} v dI/dt curve redrawn

Page 13 Omitted.

Pages 1, 4 Voltage grades revised

<u>Voltage Ratings</u>

V _{RRM}	V _{RSM}
V	V
200	300
400	500
600	700
800	900
1000	1100
1200	1300
1400	1500
1500	1600
1600	1700
	V 200 400 600 800 1000 1200 1400 1500

This Report is applicable to higher or lower voltage grades when supply has been agreed by Sales/Production.

2.0 INTRODUCTION

The diode series comprises fast recovery cold-weld capsules with all diffused silicon slices. All these diodes have controlled reverse recovery characteristics with good "S" factors.

3.0 NOTES ON THE RATINGS

(a) Square wave ratings

These ratings are given for leading edge linear rates of rise of forward current of 100 and 200A/uS.

(b) Energy per pulse characteristics

These curves enable rapid estimation of device dissipation to be obtained for conditions not covered by the frequency ratings.

Let: Ep be the Energy per pulse for a given current and pulse width, in joules.

Then
$$W_{AV} = Ep \times f$$
.

and
$$T_{SINK} = T_{J(MAX)} - W_{AV} R_{th}$$

4.0 REVERSE RECOVERY LOSS

On account of the number of circuit variables affecting reverse recovery voltage, no allowance for reverse recovery loss has been made in these ratings. The following procedure is recommended for use where it is necessary to include reverse recovery loss.

(a) Determination by Measurement

From waveforms of recovery current obtained from a high frequency shunt (see Note 1) and reverse voltage present during recovery, an instantaneous reverse recovery loss waveform must be constructed. Let the area under this waveform be A joules per pulse. A new heat sink temperature can then be evaluated from:

$$T_{SINK}$$
 (new) = T_{SINK} (original) - A $(\frac{r_{t}.10^{6}}{t} + R_{th} \times f)$
where r_{t} = 1.13 x 10⁻⁴ \sqrt{t}

t = duration of reverse recovery loss per pulse in microseconds

A = Area under reverse loss waveform per pulse in joules (W.S.)

f = rated frequency at the original heat sink temperature

The total dissipation is now given by

$$W$$
(TOT) = W (original) + Axf

NOTE 1

REVERSE RECOVERY LOSS BY MEASUREMENT

This device has a low reverse recovered charge and peak reverse recovery current. When measuring the charge care must be taken to ensure that:

- (a) a.c. coupled devices such as current transformers are not affected by prior passage of high amplitude forward current.
- (b) The measuring oscilloscope has adequate dynamic range typically 100 screen heights - to cope with the initial forward current without overload.
- (c) Measurement of reverse recovery voltage waveform should be carried out with an appropriate snubber of 0.1uF and 5 ohms in series connected across diode anode to cathode.

(b) Design Method

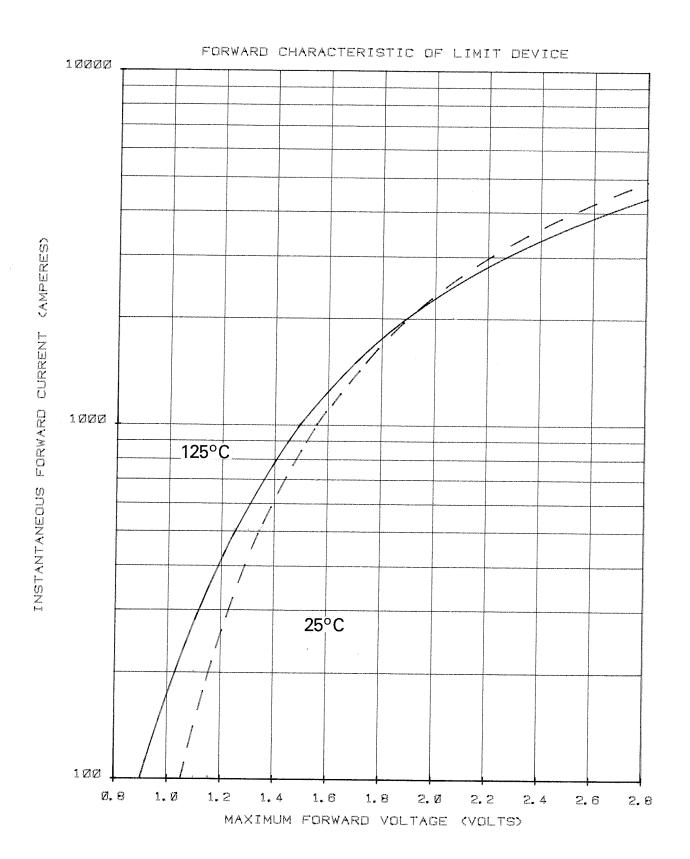
In circumstances where it is not possible to measure voltage and current conditions, or for design purposes, the additional losses may be estimated from curves on page 12.

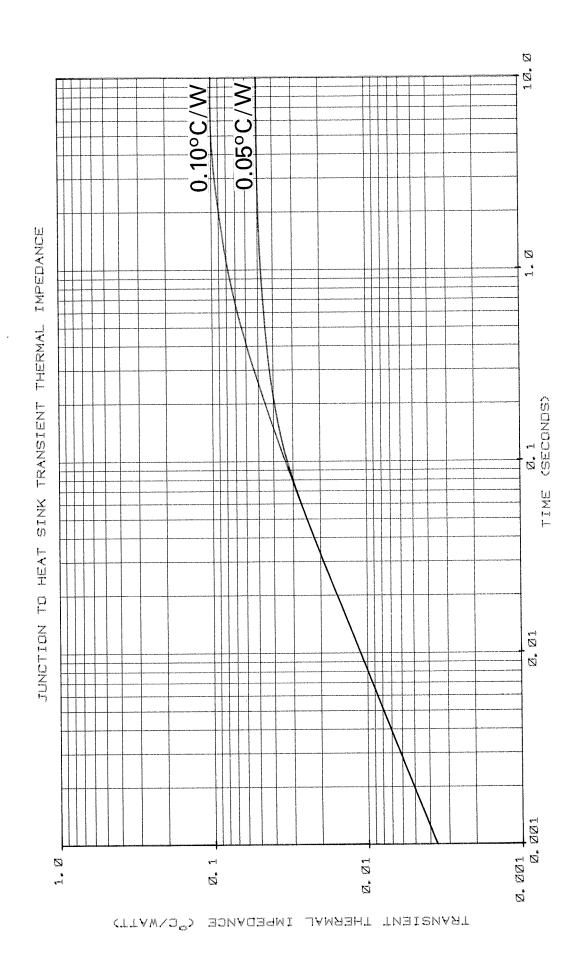
Let E be the value of energy per reverse cycle in joules (curves on page $_{12}$)

Let f be the operating frequency in Hz

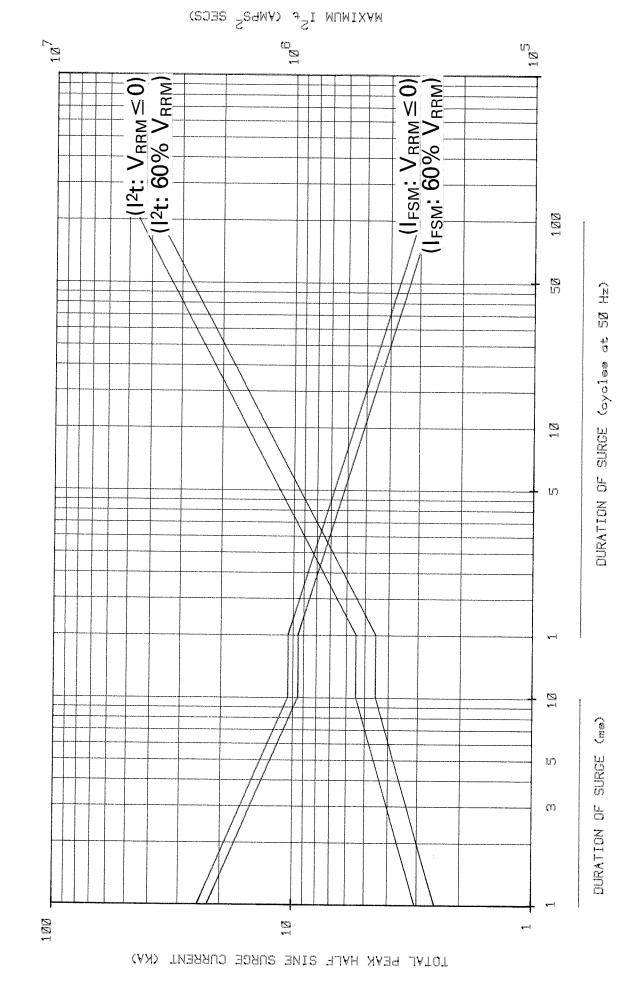
Then
$$T_{SINK}$$
 (new) = T_{SINK} (original) - E x R_{th} x f

Where $T_{\mbox{SINK}}$ new is the required maximum heat sink temperature and $T_{\mbox{SINK}}$ original is the heat sink temperature given with the frequency ratings.

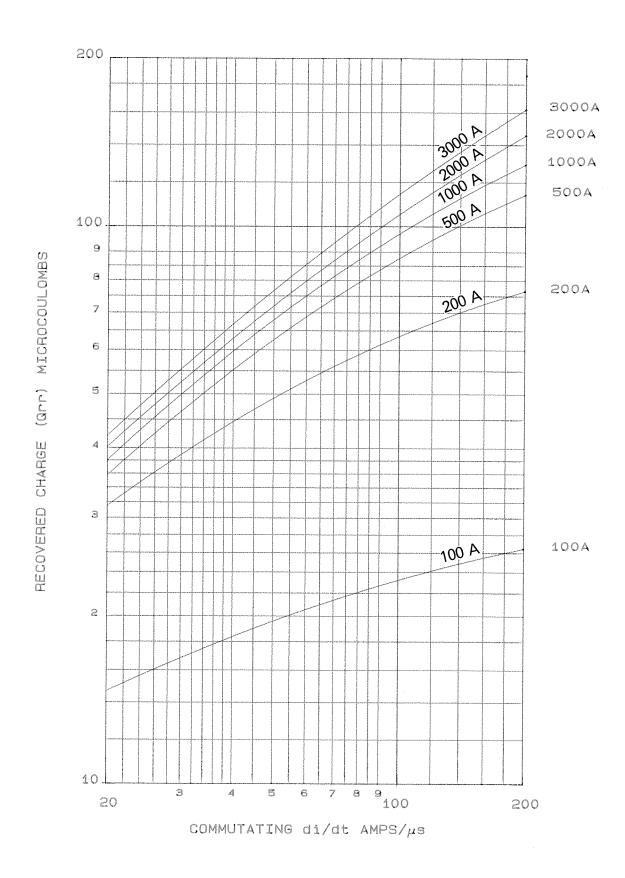


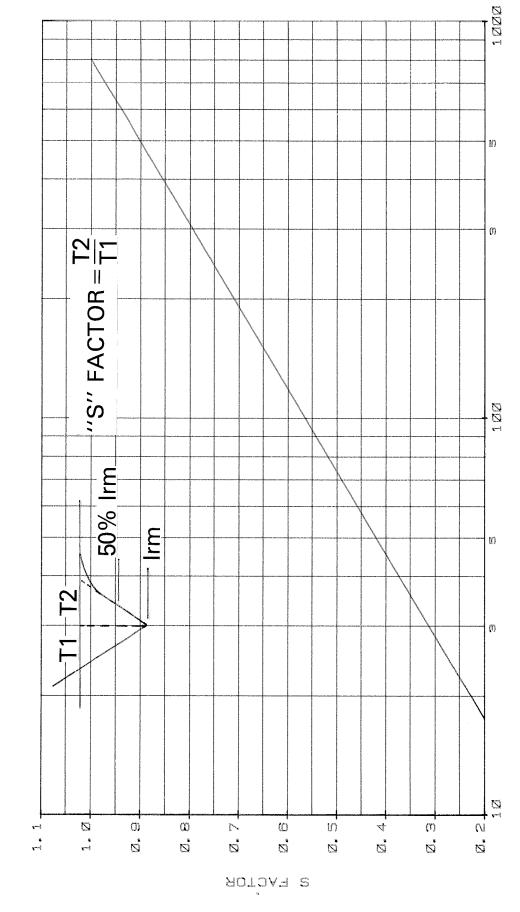






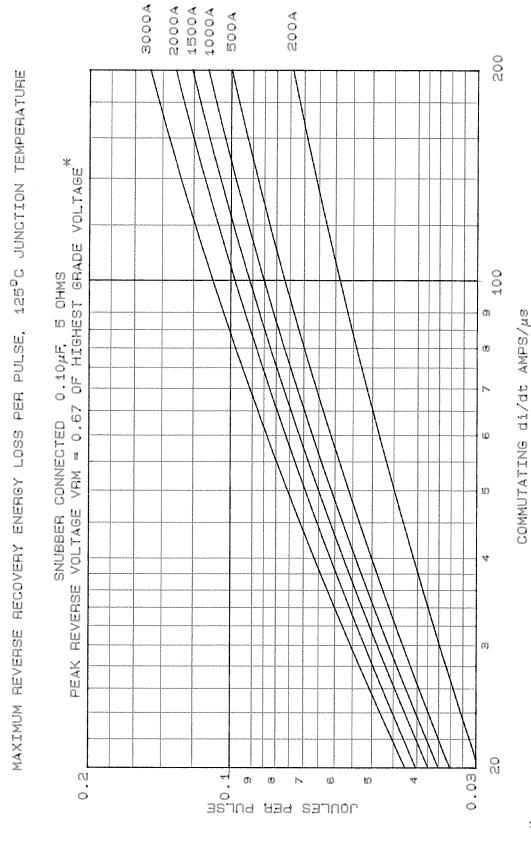
MAXIMUM RECOVERED CHARGE AT 125°C JUNCTION TEMPERATURE



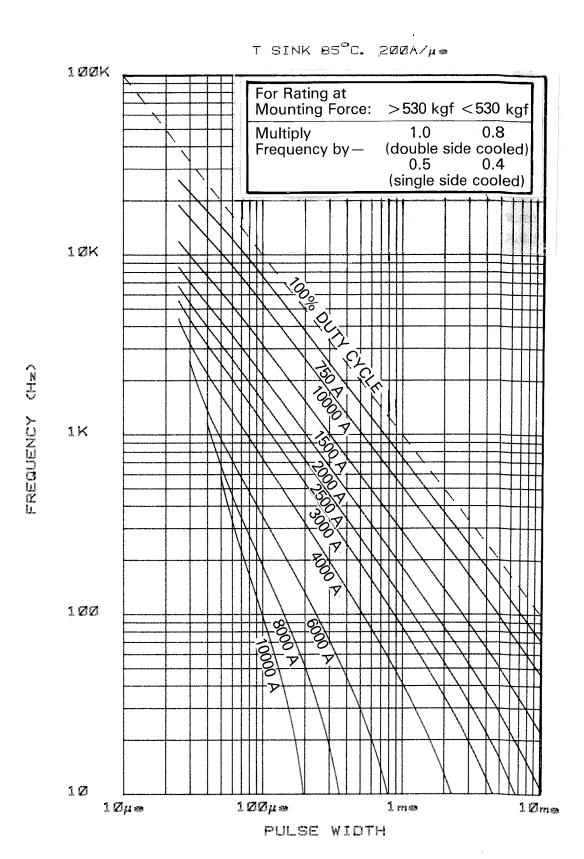


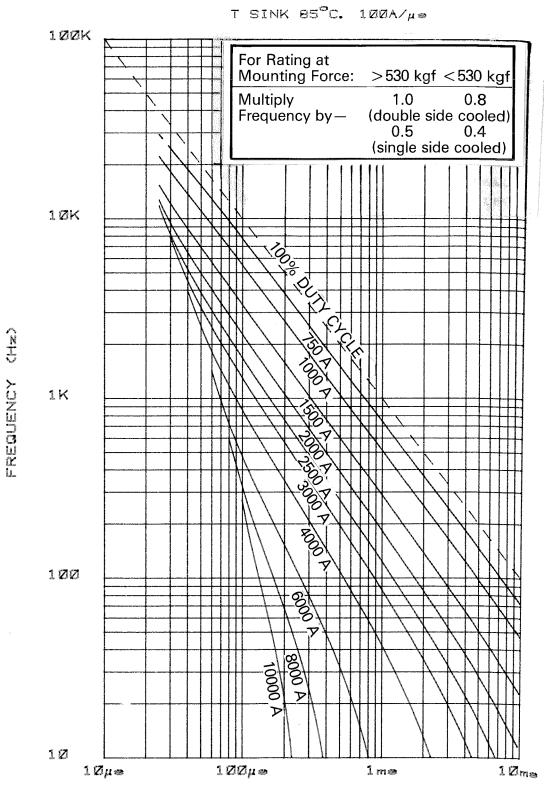
MINIMUM S FACTOR AT 125°C JUNCTION TEMPERATURE

RECOVERED CHARGE AC



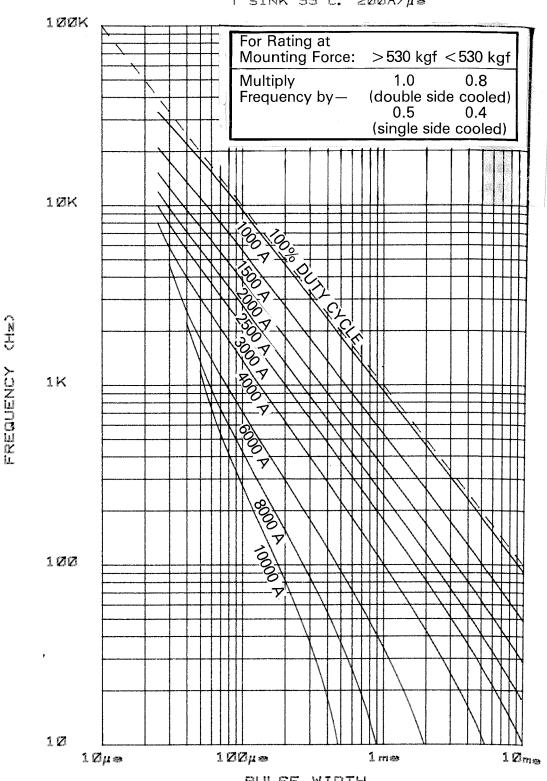
ENERGY PER PULSE SHOULD BE ADJUSTED PRO RATA WITH APPLIED PEAK RECOVERY VOLTAGE * 2 2 6



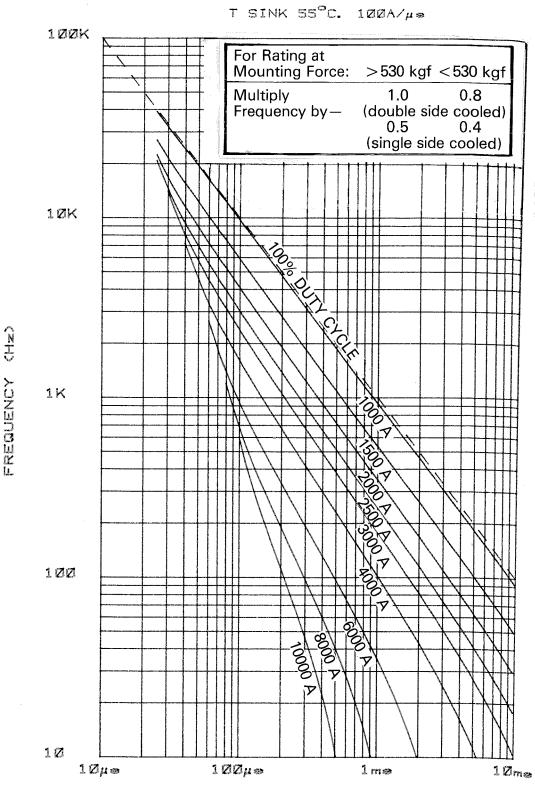


PULSE WIDTH

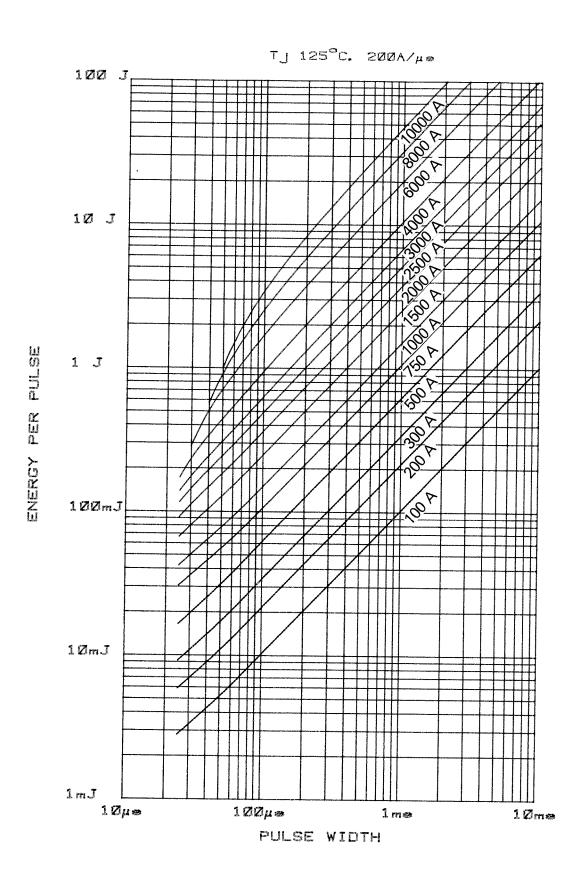
T SINK 55°C. 200A/µs

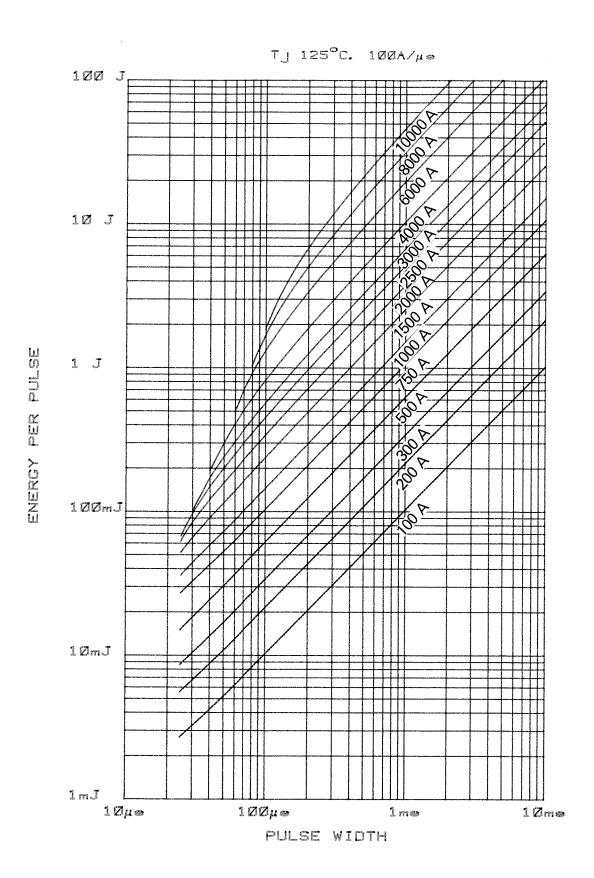


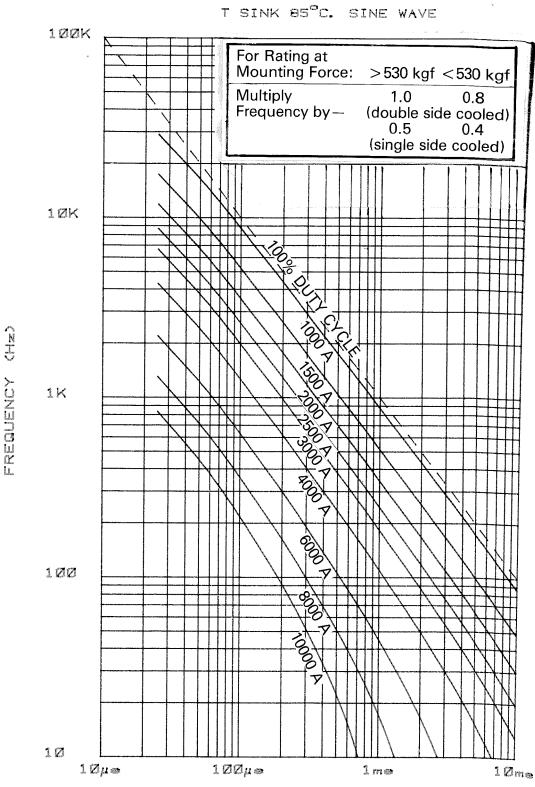
PULSE WIDTH



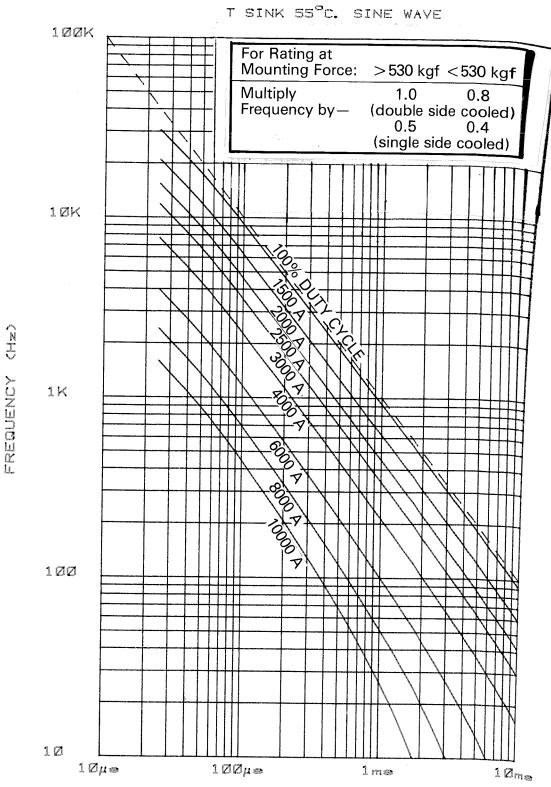
PULSE WIDTH



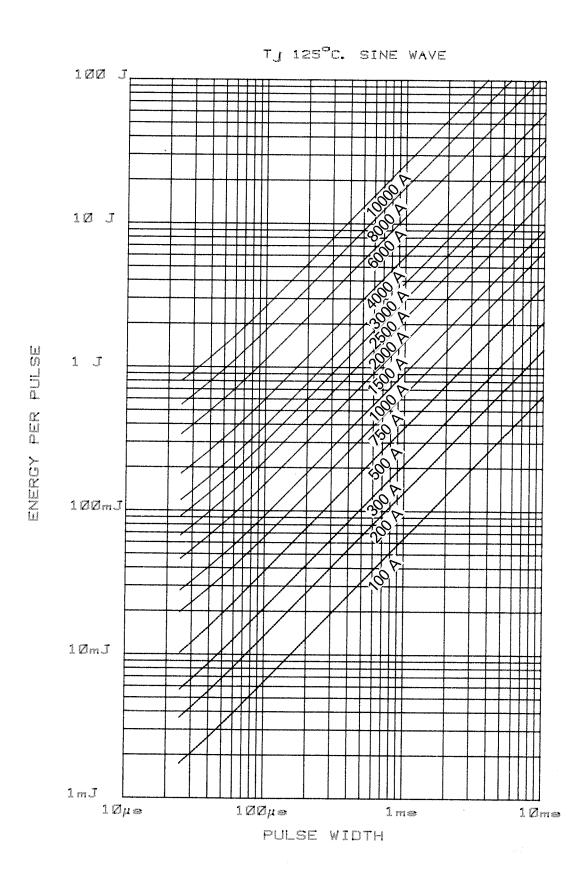




PULSE WIDTH



PULSE WIDTH



-22-SCALE INTERNATIONAL OUTLINE No. DO-2004 DRN WEIGHT. 90 GRAMS. TYPE NUMBER FINISH NICKEL PLATE. CXC190 CHKD DEVICE MARKING INCLUDES MONOGRAM, TYPE No., SPEC. APPD No. AND POLARITY SYMBOL. DEVICE MOUNTING: CLAMPING FORCE TO BE APPLIED ON & OF LOCATION HOLES AND BE EVENLY DISTRIBUTED OVER AREA OF CONTACT. FLAT TOL ON SURFACES TO WHICH DEVICE IS CLAMPED TO BE 0.04 WIDE. CLAMPING FORCE 365-530 kgf. SEE RATING REPORTS FOR DOUBLE 530-1000kgf. TIER THERMAL RESISTANCE RATINGS. SUITABLE CLAMPS: BOX TYPE 101A226B, POWER CLAMP 101A260 SERIES. ΝI Ø3.6/3.5 x 1.8 MIN DEPTH 2-HOLES. ONE IN CATHODE AND ONE IN ANODE. COMPRESSED HEIGHT. 25.1 0.3 MIN 0.3 MIN CREEP PATH OVER Ø 25. CONVOLUTIONS = 11 MIN. WESTINGHOUSE BRAKE AND SIGNAL CO. LTD. CHIPPENHAM, WILTSHIRE, SN15 1JD, ENGLAND. WESTCODE ® SEMICONDUCTORS 80 P35 THIRD ANGLE PROJECTION DIMNS. IN MILLIMETRES DRG. No.

REVISIONS